

Continental Device India Limited





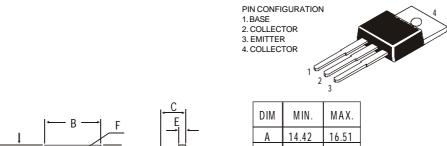


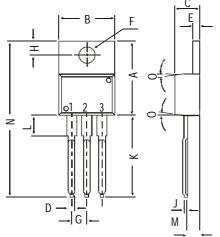
TO-220 Plastic Package

MJE2955T, MJE3055T

MJE2955T PNP PLASTIC POWER TRANSISTOR MJE3055T NPN PLASTIC POWER TRANSISTOR

General Purpose Amplifier and Switching Applications





diminsions in mm.	DIM	MIN.	MAX.
	Α	14.42	16.51
	В	9.63	10.67
	С	3.56	4.83
	D		0.90
	Ε	1.15	1.40
	F	3.75	3.88
	G	2.29	2.79
	Н	2.54	3.43
	J		0.56
	K	12.70	14.73
	Ш	2.80	4.07
	М	2.03	2.92
	N		31.24
₹	0	DEG 7	

ABSOLUTE MAXIMUM RATINGS

V_{CBO}	max.	70 V
$V_{C\!E\!O}$	max.	60 V
I_C	max.	10 A
P_{tot}	max.	75 W
T_j	max.	150 °C
V_{CEsat}	max.	1.1 V
$h_{\!F\!E}$	min	20
	max.	100
	V_{CEO} I_{C} P_{tot} T_{j} V_{CEsat}	V_{CEO} $max.$ I_{C} $max.$ P_{tot} $max.$ T_{j} $max.$ V_{CEsat} $max.$

RATINGS (at T_A =25°C unless otherwise specified)

Limiting values

0			
Collector-base voltage (open emitter)	V_{CBO}	max.	70 V
Collector-emitter voltage (open base)	$V_{C\!E\!O}$	max.	60 V
Emitter-base voltage (open collector)	V_{EBO}	max.	5.0 V

Collector current	I_C	max.	10 A
Base current	I_B	max.	6 A
Total power dissipation up to $T_C = 25^{\circ}C$	P_{tot}	max.	75 W
Derate above 25°C		max.	$0.6~W^{\circ}C$
Junction temperature	T_{j}	max.	150 ℃
Storage temperature	T_{stg}	-65 to	+150 °C
THERMAL RESISTANCE			
From junction to case	R_{thj-c}	=	1.67 °C/W
CHARACTERISTICS			
$T_{amb} = 25$ °C unless otherwise specified			
Collector cutoff current			
$I_E = 0$; $V_{CB} = 70V$	I_{CBO}	max.	1.0 mA
$I_E = 0$; $V_{CB} = 70V$; $T_C = 150^{\circ}C$	I_{CBO}	max.	10 mA
$V_{EB(off)} = 1.5V; V_{CE} = 70V$	I_{CEX}	max.	1.0 mA
$V_{EB(off)} = 1.5V; V_{CE} = 70V; T_C = 150^{\circ}C$	I_{CEX}	max.	5.0 mA
$I_B = 0; \ V_{CE} = 30V$	I_{CEO}	max.	0.7 mA
Emitter cut-off current	_		
$I_C = 0; V_{EB} = 5V$	I_{EBO}	max.	5 mA
Breakdown voltages			
$I_C = 200 \text{ mA}; I_B = 0$	$V_{CEO(sus)}^*$	min.	60 V
$I_C = 1 \text{ mA}; I_E = 0$	V_{CBO}	min.	70 V
$I_E = 1 \text{ mA}; I_C = 0$	V_{EBO}	min.	5.0 V
Saturation voltages			
$I_C = 4 A; I_B = 0.4 A$	V_{CEsat}^*	max.	1.1 V
$I_C = 10 \ A; \ I_B = 3.3 \ A$	V_{CEsat}^*	max.	8.0 V
Base-emitter on voltage			
$I_C = 4A$; $V_{CE} = 4V$	$V_{BE(on)}^*$	max.	1.8 V
D.C. current gain	22(01)		
$I_C = 4A$; $V_{CE} = 4V$	$h_{\!F\!E}^*$	min.	20
C , CL	1 L	max.	100
	•	_	_
$I_C = 10A$; $V_{CE} = 4V$	h_{FE}^*	min.	5
Transition frequency			
$I_C = 0.5A; \ V_{CE} = 10V; \ f = 500 \ KHz$	f_T	min.	2.0 MHz

^{*} Pulse test: pulse width \leq 300 μ s; duty cycle \leq 2%.

Notes

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished on the CDIL Web Site/CD is believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

CDIL strives for continuous improvement and reserves the right to change the specifications of its products without prior notice.



CDIL is a registered Trademark of Continental Device India Limited

C-120 Naraina Industrial Area, New Delhi 110 028, India.

Telephone + 91-11-579 6150 Fax + 91-11-579 9569, 579 5290
e-mail sales@cdil.com www.cdil.com